

MCP6291/2/3/4/5

1.0 mA, 10 MHz Rail-to-Rail Op Amp

Features

- Gain Bandwidth Product: 10 MHz (typ.)
- Supply Current: I_Q = 1.0 mA
- Supply Voltage: 2.4V to 5.5V
- Rail-to-Rail Input/Output
- Extended Temperature Range: -40°C to +125°C
- · Available in Single, Dual and Quad Packages
- Single with Chip Select (CS) (MCP6293)
- Dual with Chip Select (CS) (MCP6295)

Applications

- Automotive
- Portable Equipment
- Photodiode Amplifier
- Analog Filters
- Notebooks and PDAs
- Battery-Powered Systems

Available Tools

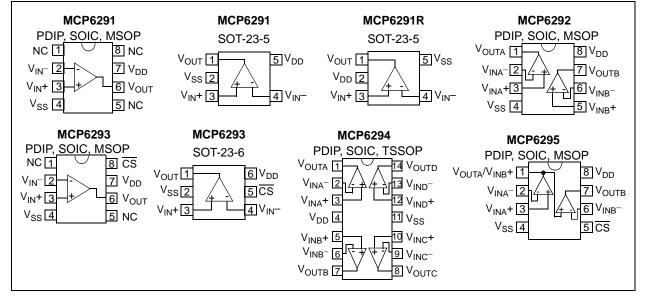
- SPICE Macro Model (at www.microchip.com)
- FilterLab[®] Software (at www.microchip.com)

Description

The Microchip Technology Inc. MCP6291/2/3/4/5 family of operational amplifiers (op amps) provide wide bandwidth for the current. This family has a 10 MHz Gain Bandwidth Product (GBWP) and a 65° phase margin. This family also operates from a single supply voltage as low as 2.4V, while drawing 1 mA (typ.) quiescent current. In addition, the MCP6291/2/3/4/5 supports rail-to-rail input and output swing, with a common mode input voltage range of V_{DD} + 300 mV to V_{SS} – 300 mV. This family of operational amplifiers is designed with Microchip's advanced CMOS process.

The MCP6295 has a Chip Select input (\overline{CS}) for dual op amps in an 8-pin package. This device is manufactured by cascading the two op amps, with the output of op amp A being connected to the non-inverting input of op amp B. The \overline{CS} input puts the device in a Low-power mode.

The MCP6291/2/3/4/5 family operates over the Extended Temperature Range of -40°C to +125°C. It also has a power supply range of 2.4V to 5.5V.



Package Types

1.0 **ELECTRICAL CHARACTERISTICS**

Absolute Maximum Ratings †

V _{DD} – V _{SS}
All Inputs and Outputs V_{SS} – 0.3V to V_{DD} + 0.3V
Difference Input Voltage $ V_{DD}-V_{SS} $
Output Short Circuit CurrentContinuous
Current at Input Pins±2 mA
Current at Output and Supply Pins±30 mA
Storage Temperature65°C to +150°C
Junction Temperature (T _J)+150°C
ESD Protection On All Pins (HBM/MM)≥ 4 kV/400V

† Notice: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

DC ELECTRICAL SPECIFICATIONS

Parameters	Sym	Min	Тур	Мах	Units	Conditions
Input Offset						
Input Offset Voltage	V _{OS}	-3.0	—	+3.0	mV	V _{CM} = V _{SS} (Note 1)
Input Offset Voltage (Extended Temperature)	V _{OS}	-5.0		+5.0	mV	$T_A = -40^{\circ}C \text{ to } +125^{\circ}C,$ $V_{CM} = V_{SS} (Note 1)$
Input Offset Temperature Drift	$\Delta V_{OS} / \Delta T_A$	_	±1.7	_	µV/°C	$T_A = -40^{\circ}C \text{ to } +125^{\circ}C,$ $V_{CM} = V_{SS} (Note 1)$
Power Supply Rejection Ratio	PSRR	70	90	—	dB	V _{CM} = V _{SS} (Note 1)
Input Bias, Input Offset Current and	Impedance					
Input Bias Current	Ι _Β	—	±1.0	_	pА	Note 2
At Temperature	Ι _Β	—	50	200	pА	T _A = +85°C (Note 2)
At Temperature	Ι _Β	—	2	5	nA	T _A = +125°C (Note 2)
Input Offset Current	I _{OS}	—	±1.0	—	pА	Note 3
Common Mode Input Impedance	Z _{CM}	—	10 ¹³ 6	—	Ω pF	Note 3
Differential Input Impedance	Z _{DIFF}	—	10 ¹³ 3	—	Ω pF	Note 3
Common Mode (Note 4)						
Common Mode Input Range	V _{CMR}	$V_{SS} - 0.3$		V_{DD} + 0.3	V	
Common Mode Rejection Ratio	CMRR	70	85	—	dB	V_{CM} = -0.3V to 2.5V, V_{DD} = 5V
Common Mode Rejection Ratio	CMRR	65	80	—	dB	V_{CM} = -0.3V to 5.3V, V_{DD} = 5V
Open-Loop Gain						
DC Open-Loop Gain (Large Signal)	A _{OL}	90	110	—	dB	$V_{OUT} = 0.2V$ to $V_{DD} - 0.2V$, $V_{CM} = V_{SS}$ (Note 1)
Output						
Maximum Output Voltage Swing	V _{OL} , V _{OH}	V _{SS} + 15		V _{DD} – 15	mV	
Output Short Circuit Current	I _{SC}	—	±25	—	mA	
Power Supply						
Supply Voltage	V _{DD}	2.4	_	5.5	V	$T_A = -40^{\circ}C \text{ to } +125^{\circ}C$
Quiescent Current per Amplifier	ا _Q	0.7	1.0	1.3	mA	$I_{O} = 0$

Electrical Characteristics: Unless otherwise indicated, $T_{4} = +25^{\circ}C$, $V_{DD} = +2.4V$ to +5.5V, $V_{CD} = GND$, $V_{CM} = V_{DD}/2$

Note 1: The MCP6295's V_{CM} for op amp B (pins V_{OUTA}/V_{INB}+ and V_{INB}-) is V_{SS} + 100 mV.

2: The current at the MCP6295's V_{INB} - pin is specified by I_B only.

3: This specification does not apply to the MCP6295's $V_{\mbox{OUTA}}/V_{\mbox{INB}}\mbox{+}$ pin.

4: The MCP6295's V_{INB}- pin (op amp B) has a common mode range (V_{CMR}) of V_{SS} + 100 mV to V_{DD} - 100 mV. The MCP6295's V_{OUTA}/V_{INB}+ pin (op amp B) has a voltage range specified by V_{OH} and V_{OL}.

AC ELECTRICAL SPECIFICATIONS

Electrical Characteristics: Unless otherwise indicated, $T_A = +25$ °C, $V_{DD} = +2.4V$ to +5.5V, $V_{SS} = GND$, $V_{CM} = V_{DD}/2$, $V_{OUT} \approx V_{DD}/2$, $R_L = 10 \text{ k}\Omega$ to $V_{DD}/2$ and $C_L = 60 \text{ pF}$.									
Parameters	Sym	Min	Тур	Max	Units	Conditions			
AC Response									
Gain Bandwidth Product	GBWP	_	10.0	_	MHz				
Phase Margin at Unity-Gain	PM	_	65	_	0				
Slew Rate	SR	_	7	_	V/µs				
Noise									
Input Noise Voltage	E _{ni}	_	3.5	_	μV _{P-P}	f = 0.1 Hz to 10 Hz			
Input Noise Voltage Density	e _{ni}	_	8.7	_	nV/√Hz	f = 10 kHz			
Input Noise Current Density	i _{ni}	_	3	_	fA/√Hz	f = 1 kHz			

TEMPERATURE SPECIFICATIONS

Electrical Characteristics: Unless otherwi	se indicated, V	_{DD} = +2.4V	to +5.5V an	d V _{SS} = GNI	D.	
Parameters	Sym	Min	Тур	Max	Units	Conditions
Temperature Ranges						
Operating Temperature Range	T _A	-40	_	+125	°C	Note
Storage Temperature Range	T _A	-65	_	+150	°C	
Thermal Package Resistances						
Thermal Resistance, 5L-SOT-23	θ_{JA}	-	256	_	°C/W	
Thermal Resistance, 6L-SOT-23	θ_{JA}	-	230	_	°C/W	
Thermal Resistance, 8L-PDIP	θ _{JA}	—	85	_	°C/W	
Thermal Resistance, 8L-SOIC	θ _{JA}	—	163	_	°C/W	
Thermal Resistance, 8L-MSOP	θ_{JA}	_	206		°C/W	
Thermal Resistance, 14L-PDIP	θ_{JA}	—	70		°C/W	
Thermal Resistance, 14L-SOIC	θ_{JA}	—	120	_	°C/W	
Thermal Resistance, 14L-TSSOP	θ_{JA}	—	100	_	°C/W	

Note: The Junction Temperature (T_J) must not exceed the Absolute Maximum specification of +150°C.

MCP6293/MCP6295 CHIP SELECT (CS) SPECIFICATIONS

Parameters	Sym	Min	Тур	Max	Units	Conditions
CS Low Specifications						
CS Logic Threshold, Low	V _{IL}	V _{SS}	—	0.2 V _{DD}	V	
CS Input Current, Low	I _{CSL}	_	0.01	_	μA	$\overline{\text{CS}} = \text{V}_{\text{SS}}$
CS High Specifications						
CS Logic Threshold, High	V _{IH}	0.8 V _{DD}	—	V _{DD}	V	
CS Input Current, High	I _{CSH}	—	0.7	2	μA	$\overline{\text{CS}} = \text{V}_{\text{DD}}$
GND Current per Amplifier	I _{SS}	—	-0.7	—	μA	$\overline{\text{CS}} = \text{V}_{\text{DD}}$
Amplifier Output Leakage	_	—	0.01	—	μA	$\overline{\text{CS}} = \text{V}_{\text{DD}}$
Dynamic Specifications (Note 1)						
CS Low to Valid Amplifier Output, Turn-on Time	t _{ON}		4	10	μs	$\label{eq:cs} \begin{array}{ c c c c } \hline \hline CS \ Low \leq 0.2 \ V_{DD}, \ G = +1 \ V/V, \\ V_{IN} = V_{DD}/2, \ V_{OUT} = 0.9 \ V_{DD}/2, \\ V_{DD} = 5.0 V \end{array}$
CS High to Amplifier Output High-Z	t _{OFF}	—	0.01	_	μs	$\label{eq:constraint} \begin{split} \overline{CS} \; High \geq 0.8 \; V_{DD}, \; G = +1 \; V/V, \\ V_{IN} = V_{DD}/2, \; V_{OUT} = 0.1 \; V_{DD}/2 \end{split}$
Hysteresis	V _{HYST}	_	0.6	_	V	V _{DD} = 5V

Note 1: The input condition (V_{IN}) specified applies to both op amp A and B of the MCP6295. The dynamic specification is tested at the output of op amp B (V_{OUTB}).

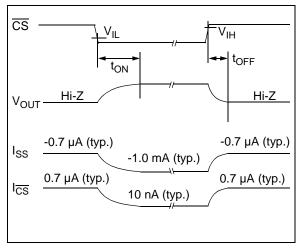


FIGURE 1-1: Timing Diagram for the Chip Select (CS) pin on the MCP6293 and MCP6295.

2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

Note: Unless otherwise indicated, $T_A = +25^{\circ}$ C, $V_{DD} = +2.4$ V to +5.5V, $V_{SS} = GND$, $V_{CM} = V_{DD}/2$, $V_{OUT} \approx V_{DD}/2$, $R_L = 10 \text{ k}\Omega$ to $V_{DD}/2$ and $C_L = 60 \text{ pF}$.

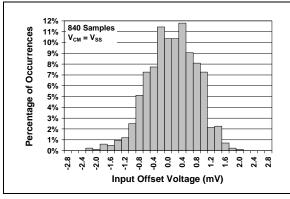


FIGURE 2-1:

Input Offset Voltage.

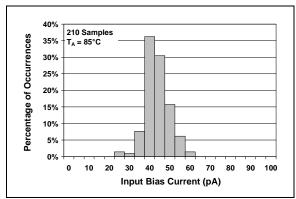


FIGURE 2-2: Input Bias Current at $T_A = +85$ °C.

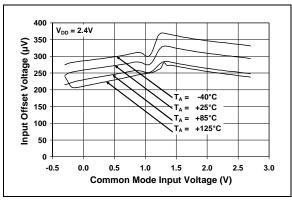


FIGURE 2-3: Input Offset Voltage vs. Common Mode Input Voltage at $V_{DD} = 2.4V$.

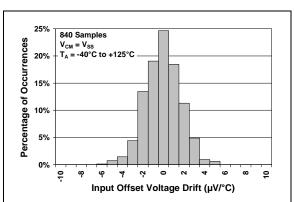


FIGURE 2-4:

Input Offset Voltage Drift.

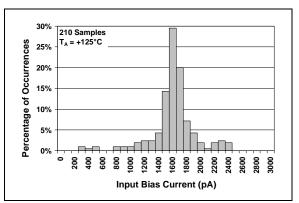


FIGURE 2-5: Input Bias Current at $T_A = +125$ °C.

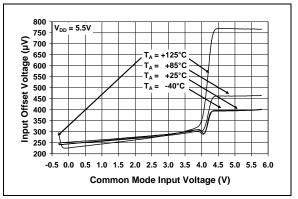


FIGURE 2-6: Input Offset Voltage vs. Common Mode Input Voltage at $V_{DD} = 5.5V$.

Note: Unless otherwise indicated, $T_A = +25^{\circ}C$, $V_{DD} = +2.4V$ to +5.5V, $V_{SS} = GND$, $V_{CM} = V_{DD}/2$, $V_{OUT} \approx V_{DD}/2$, $R_L = 10 \text{ k}\Omega$ to $V_{DD}/2$ and $C_L = 60 \text{ pF}$.

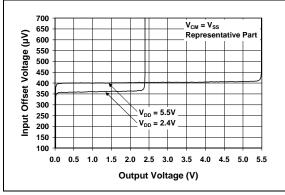


FIGURE 2-7: Output Voltage.

Input Offset Voltage vs.

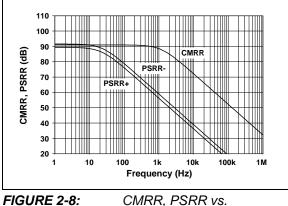


FIGURE 2-8: Frequency.

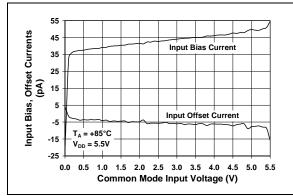


FIGURE 2-9: Input Bias, Offset Currents vs. Common Mode Input Voltage at $T_A = +85^{\circ}$ C.

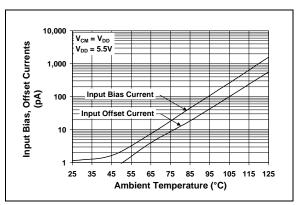


FIGURE 2-10: Input Bias, Input Offset Currents vs. Ambient Temperature.

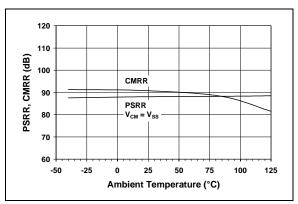


FIGURE 2-11: CMRR, PSRR vs. Ambient Temperature.

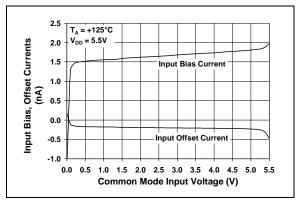


FIGURE 2-12: Input Bias, Offset Currents vs. Common Mode Input Voltage at $T_A = +125^{\circ}$ C.

Note: Unless otherwise indicated, $T_A = +25^{\circ}C$, $V_{DD} = +2.4V$ to +5.5V, $V_{SS} = GND$, $V_{CM} = V_{DD}/2$, $V_{OUT} \approx V_{DD}/2$, $R_L = 10 \text{ k}\Omega$ to $V_{DD}/2$ and $C_L = 60 \text{ pF}$.

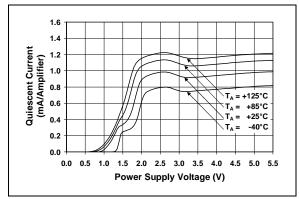


FIGURE 2-13: Quiescent Current vs. Power Supply Voltage.

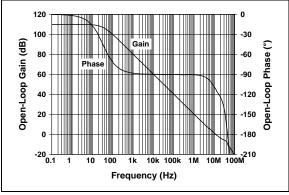


FIGURE 2-14: Open-Loop Gain, Phase vs. Frequency.

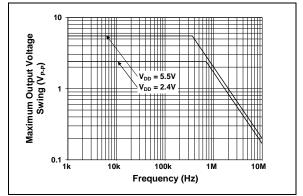


FIGURE 2-15: Maximum Output Voltage Swing vs. Frequency.

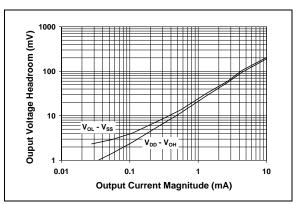


FIGURE 2-16: Output Voltage Headroom vs. Output Current Magnitude.

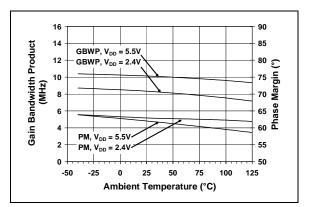


FIGURE 2-17: Gain Bandwidth Product, Phase Margin vs. Ambient Temperature.

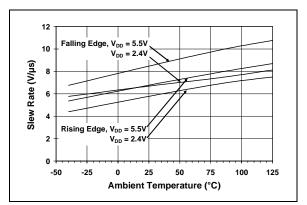


FIGURE 2-18:Slew Rate vs. AmbientTemperature.

Note: Unless otherwise indicated, $T_A = +25^{\circ}C$, $V_{DD} = +2.4V$ to +5.5V, $V_{SS} = GND$, $V_{CM} = V_{DD}/2$, $V_{OUT} \approx V_{DD}/2$, $R_L = 10 \text{ k}\Omega$ to $V_{DD}/2$ and $C_L = 60 \text{ pF}$.

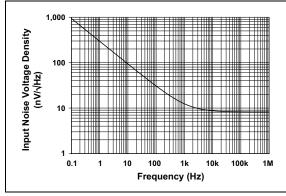


FIGURE 2-19: Input Noise Voltage Density vs. Frequency.

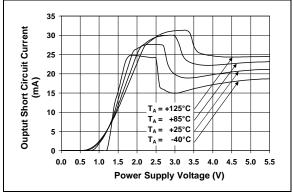


FIGURE 2-20: Output Short Circuit Current vs. Power Supply Voltage.

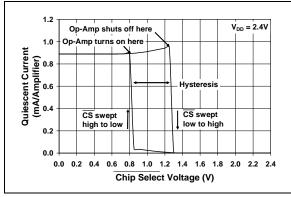


FIGURE 2-21: Quiescent Current vs. Chip Select (CS) Voltage at $V_{DD} = 2.4V$ (MCP6293 and MCP6295 only).

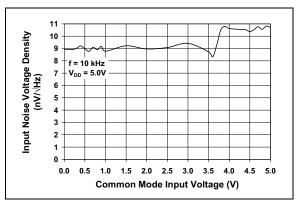
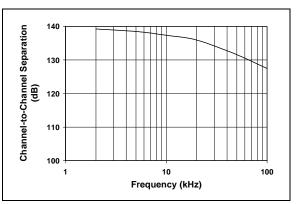
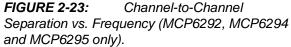


FIGURE 2-22: Input Noise Voltage Density vs. Common Mode Input Voltage at 10 kHz.





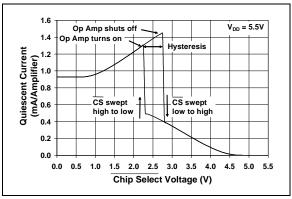


FIGURE 2-24:Quiescent Current vs.Chip Select (CS)Voltage at $V_{DD} = 5.5V$ (MCP6293 and MCP6295 only).

Note: Unless otherwise indicated, T_A = +25°C, V_{DD} = +2.4V to +5.5V, V_{SS} = GND, V_{CM} = V_{DD}/2, V_{OUT} \approx V_{DD}/2, R_L = 10 k Ω to V_{DD}/2 and C_L = 60 pF.

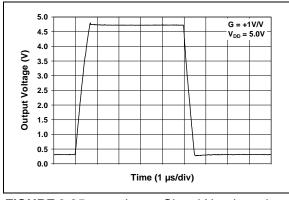
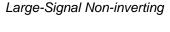


FIGURE 2-25: Pulse Response.



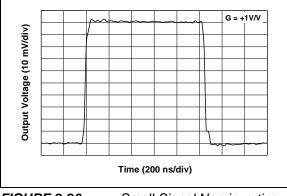


FIGURE 2-26: Pulse Response.

Small-Signal Non-inverting

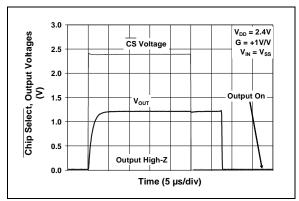


FIGURE 2-27: Chip Select (\overline{CS}) to Amplifier Output Response Time at V_{DD} = 2.4V (MCP6293 and MCP6295 only).

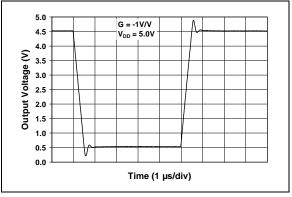


FIGURE 2-28: Large-Signal Inverting Pulse Response.

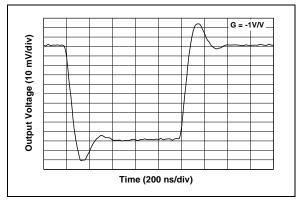
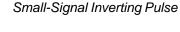


FIGURE 2-29: Small-Signa Response.



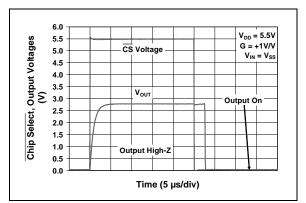


FIGURE 2-30: Chip Select (\overline{CS}) to Amplifier Output Response Time at V_{DD} = 5.5V (MCP6293 and MCP6295 only).

3.0 PIN DESCRIPTIONS

Descriptions of the pins are listed in Table 3-1 (single op amps) and Table 3-2 (dual and quad op amps).

TABLE 3-1:PIN FUNCTION TABLE FOR SINGLE OP AMPS

MCP6291 (PDIP, SOIC, MSOP)	MCP6291 (SOT-23-5)	MCP6271R (SOT-23-5)	MCP6293 (PDIP, SOIC, MSOP)	MCP6293 (SOT-23-6)	Symbol	Description			
6	1	1	6	1	V _{OUT}	Analog Output			
2	4	4	2	4	V _{IN} –	Inverting Input			
3	3	3	3	3	V _{IN} +	Non-inverting Input			
7	5	2	7	6	V _{DD}	Positive Power Supply			
4	2	5	4	2	V _{SS}	Negative Power Supply			
	_	_	8	5	CS	Chip Select			
1,5,8	_	_	1,5	_	NC	No Internal Connection			

TABLE 3-2:PIN FUNCTION TABLE FOR DUAL AND QUAD OP AMPS

MCP6292	MCP6294	MCP6295	Symbol	Description
1	1	_	V _{OUTA}	Analog Output (op amp A)
2	2	2	V _{INA} –	Inverting Input (op amp A)
3	3	3	V _{INA} +	Non-inverting Input (op amp A)
8	4	8	V _{DD}	Positive Power Supply
5	5	—	V _{INB} +	Non-inverting Input (op amp B)
6	6	6	V _{INB} –	Inverting Input (op amp B)
7	7	7	V _{OUTB}	Analog Output (op amp B)
—	8	—	V _{OUTC}	Analog Output (op amp C)
_	9		V _{INC} -	Inverting Input (op amp C)
—	10	_	V _{INC} +	Non-inverting Input (op amp C)
4	11	4	V _{SS}	Negative Power Supply
_	12		V _{IND} +	Non-inverting Input (op amp D)
—	13	_	V _{IND} -	Inverting Input (op amp D)
_	14	_	V _{OUTD}	Analog Output (op amp D)
_	_	1	V _{OUTA} /V _{INB} +	Analog Output (op amp A)/Non-inverting Input (op amp B)
	—	5	CS	Chip Select

3.1 Analog Outputs

The output pins are low-impedance voltage sources.

3.2 Analog Inputs

The non-inverting and inverting inputs are high-impedance CMOS inputs with low bias currents.

3.3 MCP6295's V_{OUTA}/V_{INB}+ Pin

For the MCP6295 only, the output of op amp A is connected directly to the non-inverting input of op amp B; this is the V_{OUTA}/V_{INB} + pin. This connection makes it possible to provide a Chip Select pin for duals in 8-pin packages.

3.4 CS Digital Input

This is a CMOS, Schmitt-triggered input that places the part into a low power mode of operation.

3.5 Power Supply (V_{SS} and V_{DD})

The positive power supply (V_{DD}) is 2.4V to 5.5V higher than the negative power supply (V_{SS}). For normal operation, the other pins are between V_{SS} and V_{DD} .

Typically, these parts are used in a single (positive) supply configuration). In this case, V_{SS} is connected to ground and V_{DD} is connected to the supply. V_{DD} will need a local bypass capacitor (typically 0.01 μ F to 0.1 μ F) within 2 mm of the V_{DD} pin. These parts need to use a bulk capacitor (within 100 mm), which can be shared with nearby analog parts.

4.0 APPLICATION INFORMATION

The MCP6291/2/3/4/5 family of op amps is manufactured using Microchip's state-of-the-art CMOS process, specifically designed for low-cost, low-power and general purpose applications. The low supply voltage, low quiescent current and wide bandwidth makes the MCP6291/2/3/4/5 ideal for battery-powered applications.

4.1 Rail-to-Rail Inputs

The MCP6291/2/3/4/5 op amp is designed to prevent phase reversal when the input pins exceed the supply voltages. Figure 4-1 shows the input voltage exceeding the supply voltage without any phase reversal.

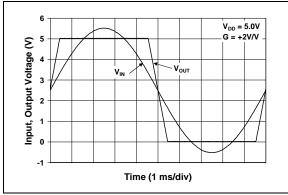


FIGURE 4-1: The MCP6291/2/3/4/5 Show No Phase Reversal.

The input stage of the MCP6291/2/3/4/5 op amps use two differential CMOS input stages in parallel. One operates at low common mode input voltage (V_{CM}), while the other operates at high V_{CM} . With this topology, the device operates with V_{CM} up to 0.3 mV above V_{DD} and 0.3 mV below V_{SS} . The Input Offset Voltage (V_{OS}) is measured at $V_{CM} = V_{SS} - 0.3$ mV and $V_{DD} + 0.3$ mV to ensure proper operation.

Input voltages that exceed the absolute maximum voltage ($V_{SS} - 0.3V$ to $V_{DD} + 0.3V$) can cause excessive current to flow into or out of the input pins. Current beyond ±2 mA can cause reliability problems. Applications that exceed this rating must be externally limited with a resistor, as shown in Figure 4-2.

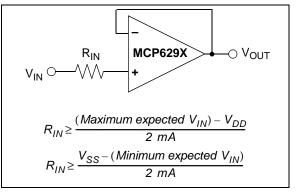


FIGURE 4-2: Input Current Limiting Resistor (R_{IN}).

4.2 Rail-to-Rail Output

The output voltage range of the MCP6291/2/3/4/5 op amp is V_{DD} – 15 mV (min.) and V_{SS} + 15 mV (max.) when R_L = 10 k Ω is connected to V_{DD}/2 and V_{DD} = 5.5V. Refer to Figure 2-16 for more information.

4.3 Capacitive Loads

Driving large capacitive loads can cause stability problems for voltage feedback op amps. As the load capacitance increases, the feedback loop's phase margin decreases and the closed-loop bandwidth is reduced. This produces gain peaking in the frequency response, with overshoot and ringing in the step response. A unity-gain buffer (G = +1) is the most sensitive to capacitive loads, though all gains show the same general behavior.

When driving large capacitive loads with these op amps (e.g., > 100 pF when G = +1), a small series resistor at the output (R_{ISO} in Figure 4-3) improves the feedback loop's phase margin (stability) by making the output load resistive at higher frequencies. The bandwidth will be generally lower than the bandwidth with no capacitive load.

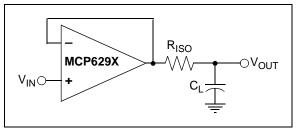


FIGURE 4-3: Output Resistor, R_{ISO} stabilizes large capacitive loads.

Figure 4-4 gives recommended R_{ISO} values for different capacitive loads and gains. The x-axis is the normalized load capacitance (C_L/G_N), where G_N is the circuit's noise gain. For non-inverting gains, G_N and the Signal Gain are equal. For inverting gains, G_N is 1+|Signal Gain| (e.g., -1 V/V gives $G_N = +2$ V/V).

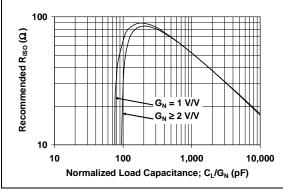


FIGURE 4-4: Recommended R_{ISO} Values for Capacitive Loads.

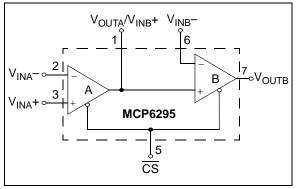
After selecting R_{ISO} for your circuit, double-check the resulting frequency response peaking and step response overshoot. Modify R_{ISO} 's value until the response is reasonable. Bench evaluation and simulations with the MCP6291/2/3/4/5 SPICE macro model are helpful.

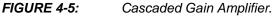
4.4 MCP629X Chip Select (CS)

The MCP6293 and MCP6295 are single and dual op amps with Chip Select (CS), respectively. When CS is pulled high, the supply current drops to 0.7 μ A (typ.) and flows through the CS pin to V_{SS}. When this happens, the amplifier output is put into a high-impedance state. By pulling CS low, the amplifier is enabled. If the CS pin is left floating, the amplifier may not operate properly. Figure 1-1 shows the output voltage and supply current response to a CS pulse.

4.5 Cascaded Dual Op Amps (MCP6295)

The MCP6295 is a dual op amp with Chip Select (\overline{CS}). The Chip Select input is available on what would be the non-inverting input of a standard dual op amp (pin 5). This is available because the output of op amp A connects to the non-inverting input of op amp B, as shown in Figure 4-5. The Chip Select input, which can be connected to a microcontroller I/O line, puts the device in Lo<u>w-power mode</u>. Refer to **Section 4.3** "**MCP6293/5 Chip Select (CS)**".





The output of op amp A is loaded by the input impedance of op amp B, which is typically $10^{13}\Omega \parallel 6 \text{ pF}$, as specified in the DC specification table (Refer to **Section 4.3 "Capacitive Loads"** for further details regarding capacitive loads).

The common mode input range of these op amps is specified in the data sheet as $V_{SS} - 300 \text{ mV}$ and $V_{DD} + 300 \text{ mV}$. However, since the output of op amp A is limited to V_{OL} and V_{OH} (20 mV from the rails with a 10 k Ω load), the non-inverting input range of op amp B is limited to the common mode input range of $V_{SS} + 20 \text{ mV}$ and $V_{DD} - 20 \text{ mV}$.

4.6 Supply Bypass

With this family of operational amplifiers, the power supply pin (V_{DD} for single supply) should have a local bypass capacitor (i.e., 0.01 μ F to 0.1 μ F) within 2 mm for good high-frequency performance. It also needs a bulk capacitor (i.e., 1 μ F or larger) within 100 mm to provide large, slow currents. This bulk capacitor can be shared with other analog parts.

4.7 PCB Surface Leakage

In applications where low input bias current is critical, Printed Circuit Board (PCB) surface-leakage effects need to be considered. Surface leakage is caused by humidity, dust or other contamination on the board. Under low humidity conditions, a typical resistance between nearby traces is $10^{12}\Omega$. A 5V difference would cause 5 pA of current to flow, which is greater than the MCP6291/2/3/4/5 family's bias current at 25°C (1 pA, typ.).

The easiest way to reduce surface leakage is to use a guard ring around sensitive pins (or traces). The guard ring is biased at the same voltage as the sensitive pin. An example of this type of layout is shown in Figure 4-6.

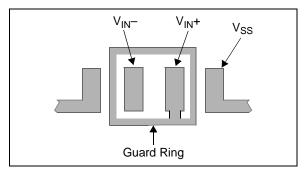


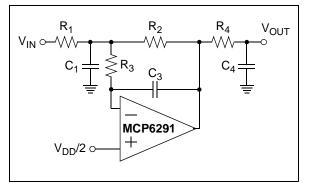
FIGURE 4-6: Example Guard Ring Layout for Inverting Gain.

- 1. For Inverting Gain and Transimpedance Amplifiers (convert current to voltage, such as photo detectors):
 - a. Connect the guard ring to the non-inverting input pin (V_{IN}+). This biases the guard ring to the same reference voltage as the op amp (e.g., $V_{DD}/2$ or ground).
 - b. Connect the inverting pin (V_{IN}-) to the input with a wire that does not touch the PCB surface.
- 2. Non-inverting Gain and Unity-Gain Buffer:
 - a. Connect the non-inverting pin (V_{IN}+) to the input with a wire that does not touch the PCB surface.
 - b. Connect the guard ring to the inverting input pin (V_{IN} -). This biases the guard ring to the common mode input voltage.

4.8 Application Circuits

4.8.1 MULTIPLE FEEDBACK LOW-PASS FILTER

The MCP6291/2/3/4/5 op amp can be used in activefilter applications. Figure 4-7 shows an inverting, thirdorder, multiple feedback low-pass filter that can be used as an anti-aliasing filter.





Multiple Feedback Low-

This filter, and others, can be designed using Microchip's FilterLab[®] software, which is available on our web site (www.microchip.com).

4.8.2 PHOTODIODE AMPLIFIER

Figure 4-8 shows a photodiode biased in the photovoltaic mode for high precision. The resistor R converts the diode current I_D to the voltage V_{OUT} . The capacitor is used to limit the bandwidth or to stabilize the circuit against the diode's capacitance (it is not always needed).

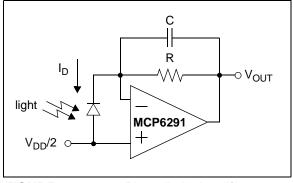


FIGURE 4-8: Photodiode Amplifier.

4.8.3 CASCADED OP AMP APPLICATIONS

The MCP6295 provides the flexibility of Low-power mode for dual op amps in an 8-pin package. The MCP6295 eliminates the added cost and space in battery-powered applications by using two single op amps with Chip Select lines or a 10-pin device with one Chip Select line for both op amps. Since the two op amps are internally cascaded, this device cannot be used in circuits that require active or passive elements between the two op amps. However, there are several applications where this op amp configuration with Chip Select line becomes suitable. The circuits below show possible applications for this device.

4.8.3.1 Load Isolation

With the cascaded op amp configuration, op amp B can be used to isolate the load from op amp A. In applications where op amp A is driving capacitive or low resistance loads in the feedback loop (such as an integrator circuit or filter circuit), the op amp may not have sufficient source current to drive the load. In this case, op amp B can be used as a buffer.

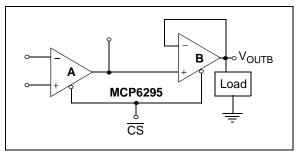


FIGURE 4-9: Isolating the Load with a Buffer.

4.8.3.2 Cascaded Gain

Figure 4-10 shows a cascaded gain circuit configuration with Chip Select. Op amps A and B are configured in a non-inverting amplifier configuration. In this configuration, it is important to note that the input offset voltage of op amp A is amplified by the gain of op amp A and B, as shown below:

$$\begin{split} V_{OUT} &= V_{IN}G_AG_B + V_{OSA}G_AG_B + V_{OSB}G_B \\ \end{split}$$

 Where:

$$\begin{split} G_A &= \text{ op amp A gain} \\ G_B &= \text{ op amp B gain} \\ V_{OSA} &= \text{ op amp A input offset voltage} \\ V_{OSB} &= \text{ op amp B input offset voltage} \end{split}$$

Therefore, it is recommended to set most of the gain with op amp A and use op amp B with relatively small gain (e.g., a unity-gain buffer).

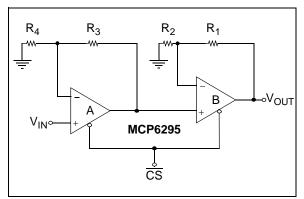


FIGURE 4-10: Cascaded Gain Circuit Configuration.

4.8.3.3 Difference Amplifier

Figure 4-11 shows op amp A as a difference amplifier with Chip Select. In this configuration, it is recommended to use well-matched resistors (e.g., 0.1%) to increase the Common Mode Rejection Ratio (CMRR). Op amp B can be used for additional gain or as a unitygain buffer to isolate the load from the difference amplifier.

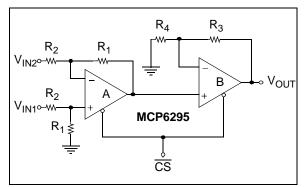


FIGURE 4-11: Di

Difference Amplifier Circuit.

4.8.3.4 Buffered Non-inverting Integrator

Figure 4-12 shows a lossy non-inverting integrator that is buffered and has a Chip Select input. Op amp A is configured as a non-inverting integrator. In this configuration, matching the impedance at each input is recommended. R_F is used to provide a feedback loop at frequencies << $1/(2\pi R_1 C_1)$ and makes this a lossy integrator (it has a finite gain at DC). Op amp B is used to isolate the load from the integrator.

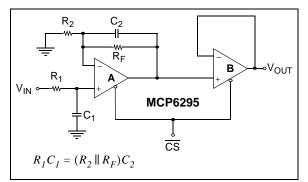


FIGURE 4-12: Buffered Non-inverting Integrator with Chip Select.

4.8.3.5 Inverting Integrator with Active Compensation and Chip Select

Figure 4-13 uses an active compensator (op amp B) to compensate for the non-ideal op amp characteristics introduced at higher frequencies. This circuit uses op amp B as a unity-gain buffer to isolate the integration capacitor C_1 from op amp A and drives the capacitor with low-impedance source. Since both op amps are matched very well, they provide a high quality integrator.

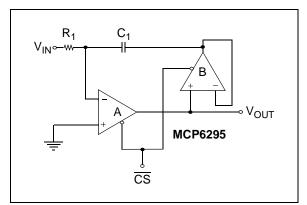


FIGURE 4-13: Integrator Circuit with Active Compensation.

4.8.3.6 Second-Order MFB Low-Pass Filter with an Extra Pole-Zero Pair

Figure 4-14 is <u>a second-order</u> multiple feedback lowpass filter with Chip Select. Use the FilterLab[®] software from Microchip to determine the R and C values for the op amp A's second-order filter. Op amp B can be used to add a pole-zero pair using C_3 , R_6 and R_7 .

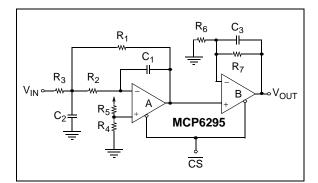


FIGURE 4-14: Second-Order Multiple Feedback Low-Pass Filter with an Extra Pole-Zero Pair.

4.8.3.7 Second-Order Sallen-Key Low-Pass Filter with an Extra Pole-Zero Pair

Figure 4-15 is a second-order, Sallen-Key low-pass filter with Chip Select. Use the FilterLab[®] software from Microchip to determine the R and C values for the op amp A's second-order filter. Op amp B can be used to add a pole-zero pair using C_3 , R_5 and R_6 .

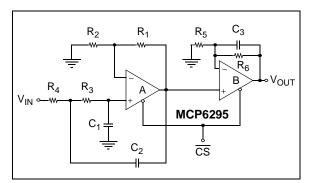


FIGURE 4-15: Second-Order Sallen-Key Low-Pass Filter with an Extra Pole-Zero Pair and Chip Select.

4.8.3.8 Capacitorless Second-Order Low-Pass filter with Chip Select

The low-pass filter shown in Figure 4-16 does not require external capacitors and uses only three external resistors; the op amp's GBWP sets the corner frequency. R_1 and R_2 are used to set the circuit gain and R_3 is used to set the Q. To avoid gain peaking in the frequency response, Q needs to be low (lower values need to be selected for R_3). Note that the amplifier bandwidth varies greatly over temperature and process. However, this configuration provides a low cost solution for applications with high bandwidth requirements.

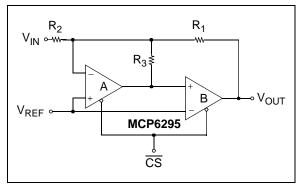


FIGURE 4-16: Capacitorless Second-Order Low-Pass Filter with Chip Select.

5.0 DESIGN TOOLS

Microchip provides the basic design tools needed for the MCP6291/2/3/4/5 family of op amps.

5.1 SPICE Macro Model

The latest SPICE macro model for the MCP6291/2/3/4/5 op amps is available on our web site at www.microchip.com. This model is intended to be an initial design tool that works well in the op amp's linear region of operation at room temperature. See the macro model file for information on its capabilities.

Bench testing is a very important part of any design and cannot be replaced with simulations. Also, simulation results using this macro model need to be validated by comparing them to the data sheet specifications and characteristic curves.

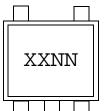
5.2 FilterLab[®] Software

Microchip's FilterLab software is an innovative tool that simplifies analog active-filter (using op amps) design. Available at no cost from our web site at www.microchip.com, the FilterLab design tool provides full schematic diagrams of the filter circuit with component values. It also outputs the filter circuit in SPICE format, which can be used with the macro model to simulate actual filter performance.

6.0 **PACKAGING INFORMATION**

6.1 **Package Marking Information**

5-Lead SOT-23 (MCP6291 and MCP6291R)

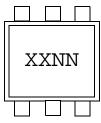


Device	Code	
MCP6291	CJNN	
MCP6291R	EVNN	
Nete: Applicat	o 5 Lood SOT 22	

Note: Applies to 5-Lead SOT-23

Example: CJ25

6-Lead SOT-23 (MCP6283)



8-Lead MSOP

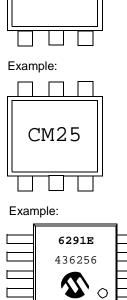
XXXXXX YWWNNN	
$\sim \mathcal{X}$	

8-Lead PDIP (300 mil)

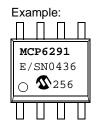


8-Lead SOIC (150 mil)

Л	Π	Π	Ĺ
XX	XXX	XXX	:
XX	XXY	YWW	I
0	S	NNN	1
		Π	



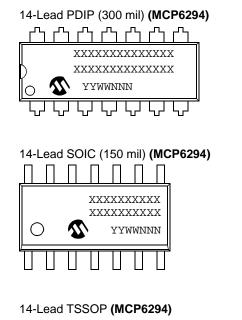
Example: <u> ריז ריז רו</u> MCP6291 E/P256 **M** 0436

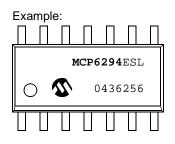


Legenc	I: XXX YY WW NNN	Customer specific information* Year code (last 2 digits of calendar year) Week code (week of January 1 is week '01') Alphanumeric traceability code
Note:	be carried	nt the full Microchip part number cannot be marked on one line, it will over to the next line thus limiting the number of available characters her specific information.

Standard marking consists of Microchip part number, year code, week code, traceability code (facility code, mask rev#, and assembly code). For marking beyond this, certain price adders apply. Please check with your Microchip Sales Office.

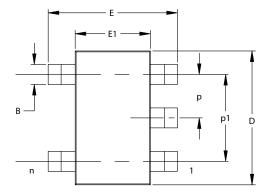
Package Marking Information (Continued)

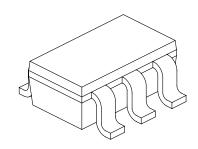


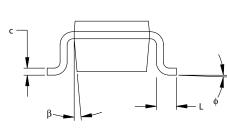


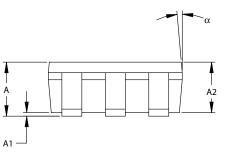
Example: 6294EST 0436 256

5-Lead Plastic Small Outline Transistor (OT) (SOT-23)









	Units		INCHES*		N	1ILLIMETERS	
Dimension	MIN	NOM	MAX	MIN	NOM	MAX	
Number of Pins	n		5				
Pitch	р		.038			0.95	
Outside lead pitch (basic)	p1		.075			1.90	
Overall Height	A	.035	.046	.057	0.90	1.18	1.45
Molded Package Thickness	A2	.035	.043	.051	0.90	1.10	1.30
Standoff	A1	.000	.003	.006	0.00	0.08	0.15
Overall Width	E	.102	.110	.118	2.60	2.80	3.00
Molded Package Width	E1	.059	.064	.069	1.50	1.63	1.75
Overall Length	D	.110	.116	.122	2.80	2.95	3.10
Foot Length	L	.014	.018	.022	0.35	0.45	0.55
Foot Angle	¢	0	5	10	0	5	10
Lead Thickness	с	.004	.006	.008	0.09	0.15	0.20
Lead Width	В	.014	.017	.020	0.35	0.43	0.50
Mold Draft Angle Top	α	0	5	10	0	5	10
Mold Draft Angle Bottom	β	0	5	10	0	5	10

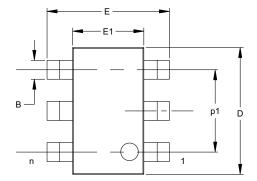
*Controlling Parameter

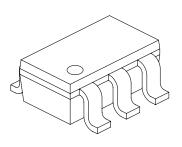
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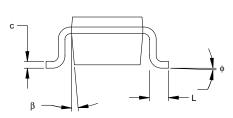
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .005" (0.127mm) per side.

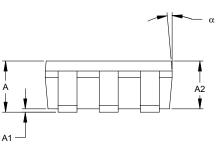
EIAJ Equivalent: SC-74A Drawing No. C04-091

6-Lead Plastic Small Outline Transistor (CH) (SOT-23)









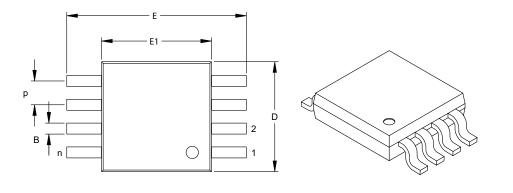
	Units		INCHES*		MILLIMETERS			
Dimensior	Dimension Limits		NOM	MAX	MIN	NOM	MAX	
Number of Pins	n		6			6		
Pitch	р		.038			0.95		
Outside lead pitch (basic)	p1		.075			1.90		
Overall Height	Α	.035	.046	.057	0.90	1.18	1.45	
Molded Package Thickness	A2	.035	.043	.051	0.90	1.10	1.30	
Standoff	A1	.000	.003	.006	0.00	0.08	0.15	
Overall Width	E	.102	.110	.118	2.60	2.80	3.00	
Molded Package Width	E1	.059	.064	.069	1.50	1.63	1.75	
Overall Length	D	.110	.116	.122	2.80	2.95	3.10	
Foot Length	L	.014	.018	.022	0.35	0.45	0.55	
Foot Angle	φ	0	5	10	0	5	10	
Lead Thickness	С	.004	.006	.008	0.09	0.15	0.20	
Lead Width	В	.014	.017	.020	0.35	0.43	0.50	
Mold Draft Angle Top	α	0	5	10	0	5	10	
Mold Draft Angle Bottom	β	0	5	10	0	5	10	
*Controlling Parameter								

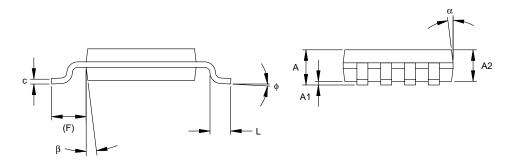
Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .005" (0.127mm) per side.

JEITA (formerly EIAJ) equivalent: SC-74A Drawing No. C04-120

8-Lead Plastic Micro Small Outline Package (MS) (MSOP)





	Units	Jnits INCHES		MILLIMETERS*		*	
Dimension Lim	Dimension Limits		NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.026 BSC			0.65 BSC	
Overall Height	A	-	-	.043	-	-	1.10
Molded Package Thickness	A2	.030	.033	.037	0.75	0.85	0.95
Standoff	A1	.000	-	.006	0.00	-	0.15
Overall Width	E	.193 TYP.			4.90 BSC		
Molded Package Width	E1	.118 BSC		3.00 BSC			
Overall Length	D		.118 BSC		3.00 BSC		
Foot Length	L	.016	.024	.031	0.40	0.60	0.80
Footprint (Reference)	F		.037 REF		0.95 REF		
Foot Angle	¢	0°	-	8°	0°	-	8°
Lead Thickness	с	.003	.006	.009	0.08	-	0.23
Lead Width	В	.009	.012	.016	0.22	-	0.40
Mold Draft Angle Top	α	5 ⁵ °	-	15°	5°	-	15°
Mold Draft Angle Bottom	β	5 ⁵ °	-	15°	5°	-	15°

*Controlling Parameter

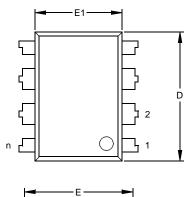
Notes:

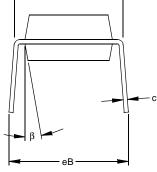
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.

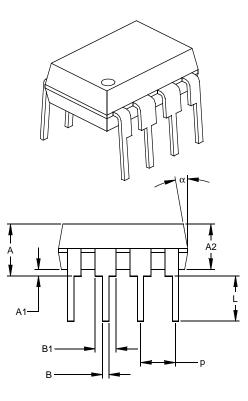
JEDEC Equivalent: MO-187

Drawing No. C04-111

8-Lead Plastic Dual In-line (P) – 300 mil (PDIP)







	Units	Units INCHES*			Ν	3	
Dimens	ion Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.100			2.54	
Top to Seating Plane	Α	.140	.155	.170	3.56	3.94	4.32
Molded Package Thickness	A2	.115	.130	.145	2.92	3.30	3.68
Base to Seating Plane	A1	.015			0.38		
Shoulder to Shoulder Width	E	.300	.313	.325	7.62	7.94	8.26
Molded Package Width	E1	.240	.250	.260	6.10	6.35	6.60
Overall Length	D	.360	.373	.385	9.14	9.46	9.78
Tip to Seating Plane	L	.125	.130	.135	3.18	3.30	3.43
Lead Thickness	С	.008	.012	.015	0.20	0.29	0.38
Upper Lead Width	B1	.045	.058	.070	1.14	1.46	1.78
Lower Lead Width	В	.014	.018	.022	0.36	0.46	0.56
Overall Row Spacing	§ eB	.310	.370	.430	7.87	9.40	10.92
Mold Draft Angle Top	α	5	10	15	5	10	15
Mold Draft Angle Bottom	β	5	10	15	5	10	15

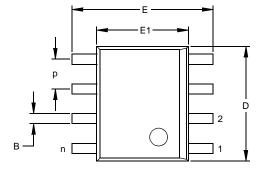
* Controlling Parameter § Significant Characteristic

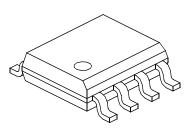
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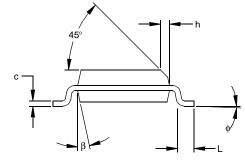
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side. JEDEC Equivalent: MS-001 Drawing No. C04-018

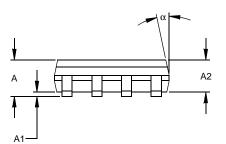
DS21812D-page 22

8-Lead Plastic Small Outline (SN) – Narrow, 150 mil (SOIC)









	Units	nits INCHES*		MILLIMETERS			
Dimensio	n Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		8			8	
Pitch	р		.050			1.27	
Overall Height	Α	.053	.061	.069	1.35	1.55	1.75
Molded Package Thickness	A2	.052	.056	.061	1.32	1.42	1.55
Standoff §	A1	.004	.007	.010	0.10	0.18	0.25
Overall Width	Е	.228	.237	.244	5.79	6.02	6.20
Molded Package Width	E1	.146	.154	.157	3.71	3.91	3.99
Overall Length	D	.189	.193	.197	4.80	4.90	5.00
Chamfer Distance	h	.010	.015	.020	0.25	0.38	0.51
Foot Length	L	.019	.025	.030	0.48	0.62	0.76
Foot Angle	φ	0	4	8	0	4	8
Lead Thickness	С	.008	.009	.010	0.20	0.23	0.25
Lead Width	В	.013	.017	.020	0.33	0.42	0.51
Mold Draft Angle Top	α	0	12	15	0	12	15
Mold Draft Angle Bottom	β	0	12	15	0	12	15

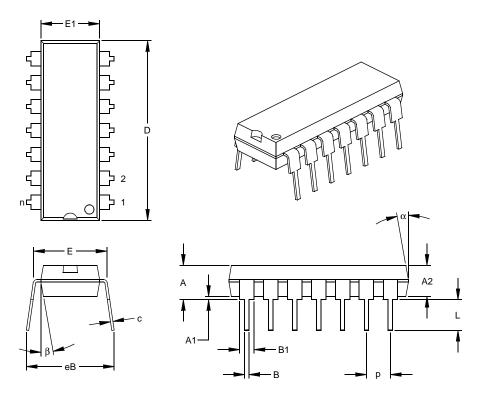
* Controlling Parameter § Significant Characteristic

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side. JEDEC Equivalent: MS-012

Drawing No. C04-057

14-Lead Plastic Dual In-line (P) – 300 mil (PDIP)

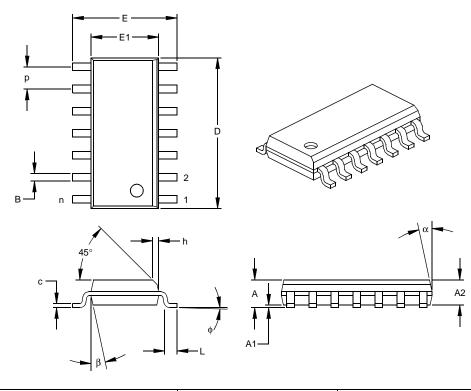


	Units		INCHES*			MILLIMETERS		
Dimensio	on Limits	MIN	NOM	MAX	MIN	NOM	MAX	
Number of Pins	n		14			14		
Pitch	р		.100			2.54		
Top to Seating Plane	Α	.140	.155	.170	3.56	3.94	4.32	
Molded Package Thickness	A2	.115	.130	.145	2.92	3.30	3.68	
Base to Seating Plane	A1	.015			0.38			
Shoulder to Shoulder Width	E	.300	.313	.325	7.62	7.94	8.26	
Molded Package Width	E1	.240	.250	.260	6.10	6.35	6.60	
Overall Length	D	.740	.750	.760	18.80	19.05	19.30	
Tip to Seating Plane	L	.125	.130	.135	3.18	3.30	3.43	
Lead Thickness	С	.008	.012	.015	0.20	0.29	0.38	
Upper Lead Width	B1	.045	.058	.070	1.14	1.46	1.78	
Lower Lead Width	В	.014	.018	.022	0.36	0.46	0.56	
Overall Row Spacing §	eB	.310	.370	.430	7.87	9.40	10.92	
Mold Draft Angle Top	α	5	10	15	5	10	15	
Mold Draft Angle Bottom	β	5	10	15	5	10	15	

* Controlling Parameter § Significant Characteristic

Notes: Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side. JEDEC Equivalent: MS-001 Drawing No. C04-005

14-Lead Plastic Small Outline (SL) - Narrow, 150 mil (SOIC)



	Units		INCHES*		MILLIMETERS			
Dimensi	Dimension Limits		NOM	MAX	MIN	NOM	MAX	
Number of Pins	n		14			14		
Pitch	р		.050			1.27		
Overall Height	Α	.053	.061	.069	1.35	1.55	1.75	
Molded Package Thickness	A2	.052	.056	.061	1.32	1.42	1.55	
Standoff §	A1	.004	.007	.010	0.10	0.18	0.25	
Overall Width	E	.228	.236	.244	5.79	5.99	6.20	
Molded Package Width	E1	.150	.154	.157	3.81	3.90	3.99	
Overall Length	D	.337	.342	.347	8.56	8.69	8.81	
Chamfer Distance	h	.010	.015	.020	0.25	0.38	0.51	
Foot Length	L	.016	.033	.050	0.41	0.84	1.27	
Foot Angle	φ	0	4	8	0	4	8	
Lead Thickness	С	.008	.009	.010	0.20	0.23	0.25	
Lead Width	В	.014	.017	.020	0.36	0.42	0.51	
Mold Draft Angle Top	α	0	12	15	0	12	15	
Mold Draft Angle Bottom	β	0	12	15	0	12	15	

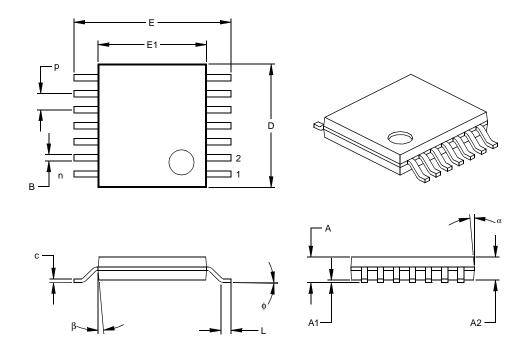
* Controlling Parameter § Significant Characteristic

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side. JEDEC Equivalent: MS-012

Drawing No. C04-065

14-Lead Plastic Thin Shrink Small Outline (ST) – 4.4 mm (TSSOP)



	Units		INCHES			MILLIMETERS*		
Dimension	Limits	MIN	NOM	MAX	MIN	NOM	MAX	
Number of Pins	n		14			14		
Pitch	р		.026			0.65		
Overall Height	Α			.043			1.10	
Molded Package Thickness	A2	.033	.035	.037	0.85	0.90	0.95	
Standoff §	A1	.002	.004	.006	0.05	0.10	0.15	
Overall Width	E	.246	.251	.256	6.25	6.38	6.50	
Molded Package Width	E1	.169	.173	.177	4.30	4.40	4.50	
Molded Package Length	D	.193	.197	.201	4.90	5.00	5.10	
Foot Length	L	.020	.024	.028	0.50	0.60	0.70	
Foot Angle	φ	0	4	8	0	4	8	
Lead Thickness	с	.004	.006	.008	0.09	0.15	0.20	
Lead Width	B1	.007	.010	.012	0.19	0.25	0.30	
Mold Draft Angle Top	α	0	5	10	0	5	10	
Mold Draft Angle Bottom	β	0	5	10	0	5	10	

* Controlling Parameter § Significant Characteristic

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .005" (0.127mm) per side. JEDEC Equivalent: MO-153

Drawing No. C04-087

APPENDIX A: REVISION HISTORY

Revision A (June 2003)

Original data sheet release.

Revision B (October 2003)

Revision C (June 2004)

Revision D (December 2004)

The following is the list of modifications:

- 1. Added SOT-23-5 packages for the MCP6291 and MCP6291R single op amps.
- 2. Added SOT-23-6 package for the MCP6293 single op amp.
- 3. Added Section 3.0 "Pin Descriptions".
- 4. Corrected application circuits (Section 4.8 "Application Circuits").
- 5. Added SOT-23-5 and SOT-23-6 packages and corrected package marking information (Section 6.0 "Packaging Information").
- 6. Added Appendix A: Revision History.

MCP6291/2/3/4/5

NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO. –	<u>×</u>	<u>/xx</u>	Exa	Examples:				
 Device Tem	perature P	ackage	a)	MCP6291-E/SN:	Extended Temperature, 8LD SOIC package.			
Range	Range	-	b)	MCP6291-E/MS:	Extended Temperature, 8LD MSOP package.			
Daviasa	MODODAL	Circle On Area	c)	MCP6291-E/P:	Extended Temperature, 8LD PDIP package.			
Device:	MCP6291: MCP6291T:	Single Op Amp Single Op Amp (Tape and Reel) (SOIC, MSOP, SOT-23-5)	d)	MCP6291T-E/OT:	Tape and Reel, Extended Temperature, 5LD SOT-23 package.			
	MCP6291RT:	Single Op Amp (Tape and Reel) (SOT-23-5)	a)	MCP6292-E/SN:	Extended Temperature, 8LD SOIC package.			
	MCP6292: MCP6292T:	Dual Op Amp Dual Op Amp	b)	MCP6292-E/MS:	Extended Temperature, 8LD MSOP package.			
	MCP6293:	(Tape and Reel) (SO <u>IC, MSOP)</u> Single Op Amp with <u>Chip Select</u>	c)	MCP6292-E/P:	Extended Temperature, 8LD PDIP package.			
	MCP6293T: MCP6294:	Single Op Amp with Chip Select (Tape and Reel) (SOIC, MSOP, SOT-23-6) Quad Op Amp	d)	MCP6292T-E/SN:	Tape and Reel, Extended Temperature, 8LD SOIC package.			
	MCP6294. MCP6294T:	Quad Op Amp Quad Op Amp (Tape and Reel) (SOIC, TSSOP)	a)	MCP6293-E/SN:	Extended Temperature, 8LD SOIC package.			
	MCP6295: MCP6295T:	Dual Op Amp with <u>Chip Select</u> Dual Op Amp with Chip Select	b)	MCP6293-E/MS:	Extended Temperature, 8LD MSOP package.			
		(Tape and Reel) (SOIC, MSOP)	c)	MCP6293-E/P:	Extended Temperature, 8LD PDIP package.			
Temperature Range:	E = -40°C	to +125°C	d)	MCP6293T-E/CH:	Tape and Reel, Extended Temperature, 6LD SOT-23 package.			
Package:		Small Outline Transistor (SOT-23), 5-lead	a)	MCP6294-E/P:	Extended Temperature, 14LD PDIP package.			
	CH = Plastic (MCP6		b)	MCP6294T-E/SL:	Tape and Reel, Extended Temperature, 14LD SOIC package.			
		DIP (300 mil Body), 8-lead, 14-lead	c)	MCP6294-E/SL:	Extended Temperature, 14LD SOIC package.			
	SL = Plastic	SOIC, (150 mil Body), 8-lead SOIC (150 mil Body), 14-lead TSSOP (4.4 mm Body), 14-lead	d)	MCP6294-E/ST:	Extended Temperature, 14LD TSSOP package.			
			a)	MCP6295-E/SN:	Extended Temperature, 8LD SOIC package.			
			b)	MCP6295-E/MS:	Extended Temperature, 8LD MSOP package.			
			c)	MCP6295-E/P:	Extended Temperature, 8LD PDIP package.			
			d)	MCP6295T-E/SN:				

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MCP6291/2/3/4/5

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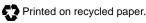
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